# NSN 5961-01-132-8060

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## **Inclosure Material:**

Plastic

**Overall Length:** 

0.200 inches

## **Terminal Length:**

12.5 millimeters

## **Overall Diameter:**

0.205 inches

## Internal Configuration:

Junction contact

## **Mounting Method:**

Terminal

### Semiconductor Material:

Silicon

## Voltage Rating In Volts Per Characteristic:

35.0 collector to base voltage/static/emitter open and 30.0 collector to emitter voltage/static/base open and 5.0 emitter to base voltage, static, collector open

## **Current Rating Per Characteristic:**

400.00 milliamperes source cutoff current

## Power Rating Per Characteristic:

300.0 milliwatts small-signal input power, common-collector

## Transfer Ratio:

120.0 static forward current transfer ratio, common-emitter and 240.0 static forward current transfer ratio, common-emitter

## Maximum Operating Tempurature Per Measurement Point:

125.0 degrees celsius junction

## **Special Features:**

Junction pattern arrangement: npn

## **Terminal Type And Quantity:**

3 uninsulated wire lead

#### Shelf Life:

N/a

#### Unit Of Measure:

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#### **Demilitarization:**

No

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